DATA SHEET



MOS FIELD EFFECT TRANSISTOR

2SK2159

N-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

The 2SK2159 is an N-channel vertical type MOS FET featuring an operating voltage as low as 1.5 V. Because it can be driven on a low voltage and it is not necessary to consider driving current, the 2SK2159 is suitable for driving actuators of low-voltage portable systems such as headphone stereo sets and camcorders.

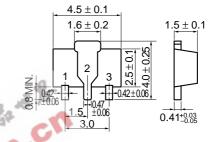
FEATURES

- · Capable of drive gate with 1.5 V
- Small Rds(on)

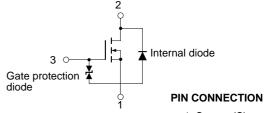
 $R_{DS(on)} = 0.7 \Omega MAX$. @VGS = 1.5 V, $I_D = 0.1 A$

 $R_{DS(on)} = 0.3 \Omega MAX$. $@V_{GS} = 4.0 V$, $I_{D} = 1.0 A$

PACKAGE DIMENSIONS (in millimeters)



EQUIVALENT CIRCUIT



1. Source (S)

2. Drain (D)

Marking: NW 3. Gate (G)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C)

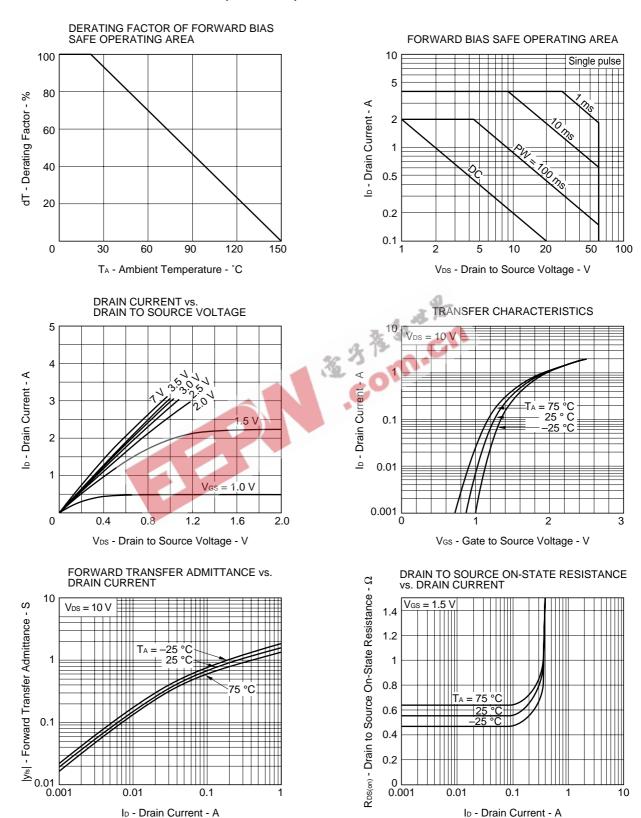
PARAMETER	SYMBOL	TEST CONDITIONS	RATINGS	UNIT
Drain to Source Voltage	Voss	V _{GS} = 0	60	V
Gate to Source Voltage	Vgss	V _{DS} = 0	±14	V
Drain Current (DC)	I _{D(DC)}		±2.0	Α
Drain Current (pulse)	ID(pulse)	PW ≤ 10 ms, Duty Cycle ≤ 50 %	±4.0	А
Total Power Dissipation	Рт	Mounted on 16 $\text{cm}^2\times 0.7$ mm ceramic substrate.	2.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

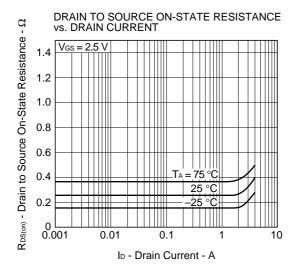


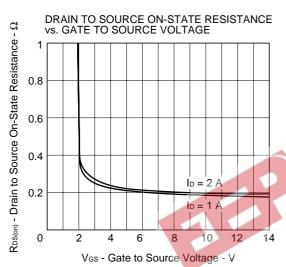
ELECTRICAL CHARACTERISTICS (TA = 25 °C)

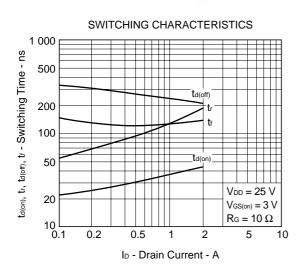
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT			
Drain Cut-off Current	Ipss	V _{DS} = 60 V, V _{GS} = 0			1.0	μΑ			
Gate Leakage Current	Igss	$V_{GS} = \pm 14 \text{ V}, V_{DS} = 0$			±10	μΑ			
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	0.5	0.9	1.1	V			
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 1.0 A	0.4			S			
Drain to Source On-state Resistance	RDS(on)1	Vgs = 1.5 V, ID = 0.1 A		0.55	0.7	Ω			
Drain to Source On-state Resistance	RDS(on)2	Vgs = 2.5 V, ID = 1.0 A		0.27	0.5	Ω			
Drain to Source On-state Resistance	RDS(on)3	Vgs = 4.0 V, ID = 1.0 A		0.22	0.3	Ω			
Input Capacitance	Ciss	V _{DS} = 10 V, V _{GS} = 0,		319		pF			
Output Capacitance	Coss	f = 1.0 MHz		109		pF			
Reverse Transfer Capacitance	Crss			22		pF			
Turn-On Delay Time	td(on)	V _{DD} = 25 V, I _D = 1.0 A		38		ns			
Rise Time	tr	$V_{GS(on)} = 3 \text{ V}, \text{ Rg} = 10 \Omega$		128		ns			
Turn-Off Delay Time	td(off)	$R_L = 25 \Omega$	五石	237		ns			
Fall Time	tf	7. 30		130		ns			
Turn-Off Delay Time t _t (a) R _L = 25 Ω 237 ns Fall Time t _t 130 ns									

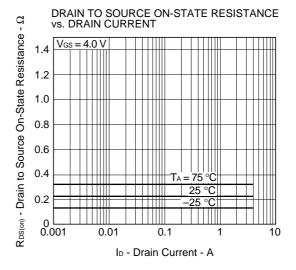
TYPICAL CHARACTERISTICS (TA = 25 °C)

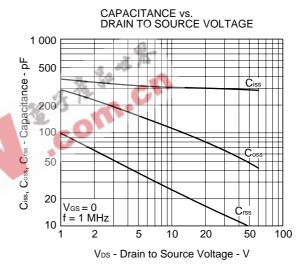


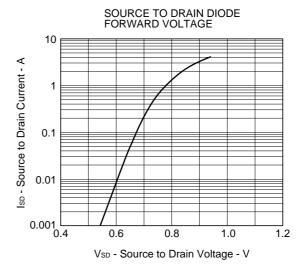














REFERENCE

Document Name	Document No.		
NEC semiconductor device reliability/quality control system	TEI-1202		
Quality grade on NEC semiconductor devices	IEI-1209		
Semiconductor device mounting technology manual	C10535E		
Guide to quality assurance for semiconductor devices	MEI-1202		
Semiconductor selection guide	X10679E		



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NEC 2SK2159

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

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The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.

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